

BD440/442

Medium Power Linear and Switching Applications

Complement to BD439, BD441 respectively



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage		
	: BD440	- 60	V
	: BD442	- 80	V
V _{CES}	Collector-Emitter Voltage		
	: BD440	- 60	V
	: BD442	- 80	V
V _{CEO}	Collector-Emitter Voltage		
	: BD440	- 60	V
	: BD442	- 80	V
V _{EBO}	Emitter-Base Voltage	- 5	V
I _C	Collector Current (DC)	- 4	Α
I _{CP}	*Collector Current (Pulse)	- 7	Α
I _B	Base Current	- 1	Α
P _C	Collector Dissipation (T _C =25°C)	36	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 65 ~ 1 50	°C

Electrical Characteristics T_{C} =25°C unless otherwise noted

Symbol	Paramete	r	Test Condition	Min.	Тур.	Max.	Units
V _{CEO} (sus)	Collector-Emitter Sustaining	g Voltage					
		: BD440	$I_C = -100 \text{mA}, I_B = 0$	-60			V
		: BD442		-80			V
Сво	Collector Cut-off Current	: BD440	$V_{CB} = -60V, I_{E} = 0$			- 100	μΑ
		: BD442	$V_{CB} = -80V, I_{E} = 0$	1		- 100	μΑ
ces	Collector Cut-off Current	: BD440	$V_{CE} = -60V, V_{BE} = 0$			- 100	μΑ
		: BD442	$V_{CE} = -80V, V_{BE} = 0$			- 100	μΑ
EBO	Emitter Cut-off Current		$V_{EB} = -5V, I_{C} = 0$			- 1	mA
h _{FE}	* DC Current Gain	: BD440	$V_{CE} = -5V, I_{C} = -10mA$	20	140		
	:	BD442		15	140		
	:	BD440	$V_{CE} = -1V$, $I_{C} = -500$ mA	40	140		
	:	BD442		40	140		
	:	BD440	$V_{CF} = -1V, I_{C} = -2A$	25			
	:	BD442	02 0	15			
V _{CE} (sat)	* Collector-Emitter Saturation	n Voltage	$I_C = -2A$, $I_B = -0.2A$			- 0.8	V
V _{BE} (on)	* Base-Emitter ON Voltage		$V_{CE} = -5V, I_{C} = -10mA$		-0.58		V
'			$V_{CE} = -1 \text{ V}, I_{C} = -2 \text{A}$	ļ		- 1.5	V
·	Current Gain Bandwidth Pr	oduct	$V_{CF} = -1V, I_{C} = -250 \text{mA}$	3			MHz

Typical Characteristics

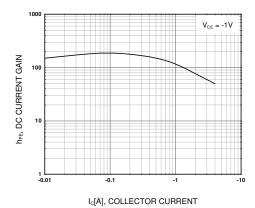


Figure 1. DC current Gain

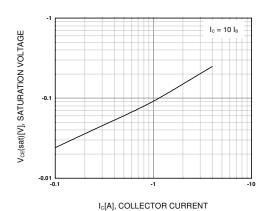


Figure 2. Collector-Emitter Saturation Voltage

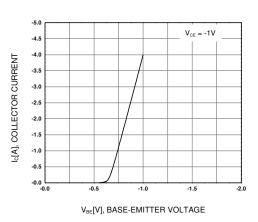


Figure 3. Base-Emitter On Voltage

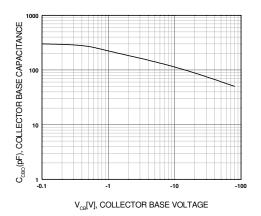


Figure 4. Collector-Base Capacitance

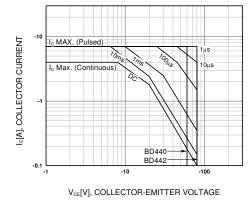


Figure 5. Safe Operating Area

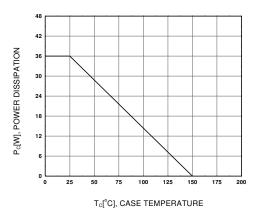


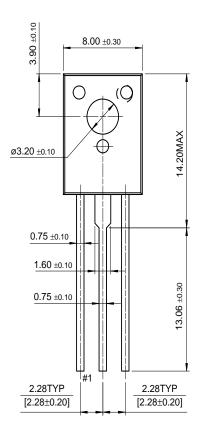
Figure 6. Power Derating

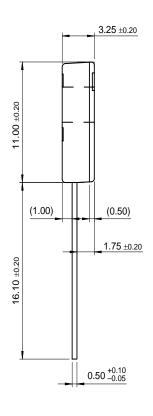
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BD440/442

Package Demensions

TO-126





Dimensions in Millimeters

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DenseTrench™	GTO™	QFET™	TinyLogic™
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Rev. H2

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